

REMARKS

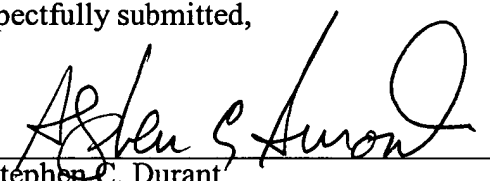
In the unlikely event that the transmittal letter is separated from this document and the Patent Office determines that an extension and/or other relief is required, applicant petitions for any required relief including extensions of time and authorizes the Assistant Commissioner to charge the cost of such petitions and/or other fees due in connection with the filing of this document to **Deposit Account No. 03-1952**. However, the Assistant Commissioner is not authorized to charge the cost of the issue fee to the Deposit Account.

Attached hereto is a marked-up version of the changes made to the specification and claims by the current amendment. The attached page is captioned **"Version with markings to show changes made."**

Respectfully submitted,

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In the specification:

Paragraph beginning at page 1, lines 1-5 have been amended as follows:

[This application is a continuation-in-part of patent application Serial No. 08/449,140, filed May 24, 1995, by inventors Kurt Petersen; Nadim Maluf, Wendell McCulley; John Logan and Erno Klaassen, entitled, "Single Crystal Silicon Sensor With High Aspect Ratio and Curvilinear Structures and Associated Method".]

-- This application is a continuation of application Serial No. 08/652,867, filed May 23, 1996, now allowed, which is a continuation-in-part of application Serial No. 08/449,140, filed May 24, 1995, which issued as U.S. Patent No. 6,084,257, issued date July 4, 2000.--

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